TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74AC299P,TC74AC299F

#### 8-Bit PIPO Shift Register with Asynchronousclear

The TC74AC299 is an advanced high speed CMOS 8-BIT PIPO SHIFT REGISTER fabricated with silicon gate and double-layer metal wiring  $C^2MOS$  technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It has a four modes (HOLD, SHIFT LEFT, SHIFT RIGHT and LOAD DATA) controlled by the two selection inputs (S0, S1).

When one or both enable ( $\overline{G1}$ ,  $\overline{G2}$ ) are high, the eight I/O outputs are forced to the high-impedance state; however, sequential operation or clearing of the register is not affected.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features (Note 1)(Note 2)

- High speed:  $f_{max} = 150 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 8 \mu A \text{ (max)}$  at  $T_a = 25^{\circ}C$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min) Capability of driving 50  $\Omega$

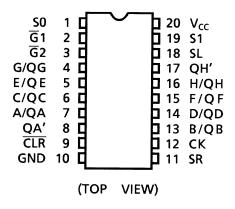
tansmission lines.

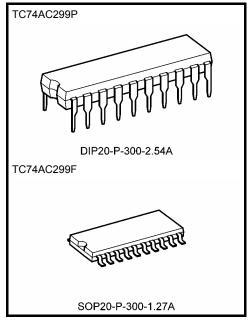
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2 to 5.5 V
- Pin and function compatible with 74F299



Note 2: All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors.

# Pin Assignment

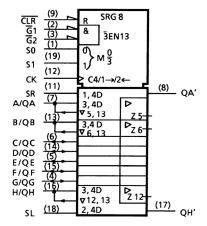




Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.)

## **IEC Logic Symbol**



#### **Truth Table**

Mode		Inputs									Outputs	
	CLR	Function select		Outputs Control		014	Serial		A (O A		0.47	0111
		S1	S0	G1 (Note)	G2 (Note)	CK	SL	SR	A/QA	H/QH	QA'	QH'
	L	Н	Н	Х	Х	Х	Х	Х	Z	Z	L	L
Clear	L	L	Х	L	L	Х	Х	Х	L	L	L	L
	L	Х	L	L	L	Х	Х	Х	L	L	L	L
Hold	Н	L	L	L	L	Х	Х	Х	QA0	QH0	QA0	QH0
Shift	Н	L	Н	L	L		Х	Н	Н	QGn	Н	QGn
Right	Н	L	Н	L	L		Х	L	L	QGn	L	QGn
Shift	Н	Н	L	L	L		Н	Х	QBn	Н	QBn	Н
Left	Н	Н	L	L	L		L	Х	QBn	L	QBn	L
Load	Н	Н	Н	Х	Х		Х	Х	а	h	а	h

Note: When one or both output controls are high, the eight input/output terminals are in the high-impedance state; however sequential or clearing of the register is not affected.

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Z: High impedance

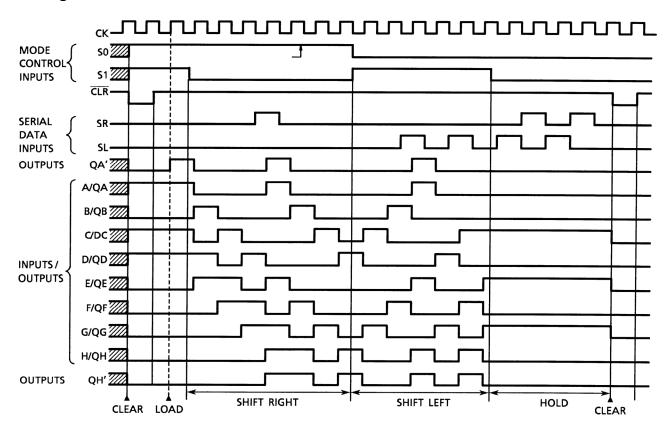
Qn0: The level of Qn before the indicated steady-state input conditions were established.

Qnn: The level of Qn before the most recent active transition indicated by  $\downarrow$  or  $\uparrow$ .

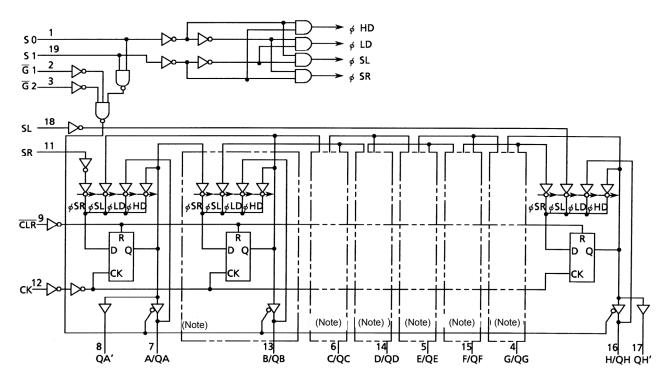
a, h: The level of the steady-state inputs A, H, respectively.

X: Don't care

## **Timing Chart**



## **System Diagram**



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Note: Equivalent circuits

### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	−0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±250	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to  $65^{\circ}C$ . From Ta = 65 to  $85^{\circ}C$  a derating factor of -10 mW/°C should be applied up to 300 mW.

## **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 100 ( $V_{CC} = 3.3 \pm 0.3 \text{ V}$ ) 0 to 20 ( $V_{CC} = 5 \pm 0.5 \text{ V}$ )	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol					-	Γa = 25°(		Ta = -40 to 85°C		Unit	
Sharasteristics	Cymbol .				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	J	
					2.0	1.50	_	_	1.50	_	V	
High-level input voltage	$V_{IH}$	_			3.0	2.10	_	_	2.10	_		
				5.5	3.85	_	_	3.85	_			
					2.0	_	_	0.50	_	0.50		
Low-level input voltage	$V_{IL}$		_		3.0	_	_	0.90	_	0.90	V	
3					5.5	_	_	1.65	_	1.65		
					2.0	1.9	2.0	_	1.9	_		
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA		3.0	2.9	3.0	_	2.9	_		
High-level output	V <sub>OH</sub>				4.5	4.4	4.5	5 — 4.4 —		_	V	
voltage	VOH		I <sub>OH</sub> = -4 mA		3.0	2.58	_	_	2.48	_	V	
			I <sub>OH</sub> = -24 mA		4.5	3.94	_	_	3.80	_		
			$I_{OH} = -75 \text{ mA}$	(Note)	5.5	_	_	_	3.85	_		
					2.0	_	0.0	0.1	_	0.1		
			$I_{OL} = 50 \mu A$		3.0	_	0.0	0.1	_	0.1		
Low-level output	$V_{OL}$	V <sub>IN</sub> = V <sub>IH</sub> or			4.5	_	0.0	0.1	_	0.1	\/	
voltage	VOL	VIT AIH OI	I <sub>OL</sub> = 12 mA		3.0	_	_	0.36	_	0.44	V	
			I <sub>OL</sub> = 24 mA		4.5	_	_	0.36	_	0.44		
			$I_{OL} = 75 \text{ mA}$	(Note)	5.5	_	_	_	_	1.65		
3-state output off-state current	l <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		5.5	_	_	±0.5	_	±5.0	μА		
		V <sub>OUT</sub> = V <sub>CC</sub> or GND									·	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μА		
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5		_	8.0	_	80.0	μА		

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

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# Timing Recommended Operating Conditions (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = -40 to 85°C	Unit	
			V <sub>CC</sub> (V)	Limit	Limit		
Minimum pulse width	t <sub>W (L)</sub>		$3.3 \pm 0.3$	8.0	8.0	no	
(CK)	t <sub>W (H)</sub>	_	$5.0 \pm 0.5$	5.0	5.0	ns	
Minimum pulse width			$3.3 \pm 0.3$	7.0	7.0		
(CLR)	t <sub>W (L)</sub>	_	$5.0 \pm 0.5$	5.0	5.0	ns	
Minimum set-up time			$3.3 \pm 0.3$	6.0	6.0		
(SL, SR, A~H)	t <sub>s</sub>	_	$5.0 \pm 0.5$	4.0	4.0	ns	
Minimum set-up time			$3.3\pm0.3$	11.9	13.6		
(S0, S1)	t <sub>s</sub>	_	$5.0 \pm 0.5$	7.0	7.0	ns	
Minimum hold time			$3.3 \pm 0.3$	1.0	1.0		
(SL, SR, A~H)	t <sub>h</sub>	_	$5.0 \pm 0.5$	1.0	1.0	ns	
Minimum hold time	_		$3.3 \pm 0.3$	0.0	0.0		
(S0, S1)	t <sub>h</sub>	_	$5.0 \pm 0.5$	0.0	0.0	ns	
Minimum removal time			$3.3\pm0.3$	5.0	5.0		
(CLR)	t <sub>rem</sub>	_	$5.0 \pm 0.5$	3.0	3.0	ns	

# AC Characteristics (CL = 50 pF, RL = 500 $\Omega$ , input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Test Condition		Га = 25°C		Ta = -40 to 85°C		Unit
	•		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay time	t <sub>pLH</sub>	_	$3.3\pm0.3$	_	10.6	18.4	1.0	21.0	ns
(CK-QA', QH')	$t_{pHL}$		$5.0 \pm 0.5$	_	6.8	10.5	1.0	12.0	
Propagation delay time	t <sub>pLH</sub>	_	$3.3\pm0.3$	_	8.1	14.0	1.0	16.0	ns
(CLR -QA', QH')	$t_{pHL}$		$5.0\pm0.5$	_	6.1	9.2	1.0	10.5	
Propagation delay time	t <sub>pLH</sub>	<del></del>	3.3 ± 0.3	_	10.9	19.3	1.0	22.0	ns
(CK-QA~QH)	t <sub>pHL</sub>		$5.0\pm0.5$	_	7.3	10.5	1.0	12.0	
Propagation delay time	t <sub>pLH</sub>	_	3.3 ± 0.3	_	9.8	16.7	1.0	19.0	ns
( CLR -QA~QH)	$t_{pHL}$		$5.0\pm0.5$	_	6.7	10.9	1.0	12.4	
Output enable time	t <sub>pZL</sub>	_	$3.3 \pm 0.3$	_	9.9	17.5	1.0	20.0	ns
Cutput oriable time	t <sub>pZH</sub>		$5.0 \pm 0.5$	_	6.6	9.6	1.0	11.0	
Output disable time	$t_{pLZ}$	_	$3.3 \pm 0.3$	_	8.1	14.0	1.0	16.0	ns
Culput disable time	$t_{pHZ}$		$5.0 \pm 0.5$	_	6.4	9.6	1.0	11.0	113
Maximum clock	f <sub>max</sub>		$3.3 \pm 0.3$	45	90	_	45	_	MHz
frequency	Imax	_	$5.0 \pm 0.5$	80	140	_	80	_	IVII IZ
Input capacitance	C <sub>IN</sub>			_	5	10	_	10	pF
Bus input capacitance	C <sub>I/O</sub>	_		_	13	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)	_		_	137	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

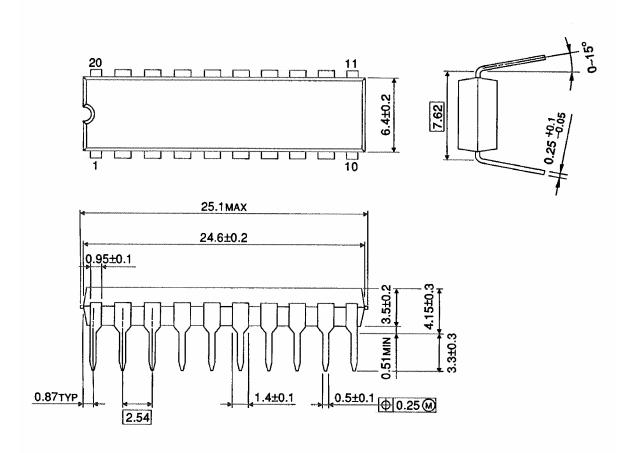
Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

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# **Package Dimensions**

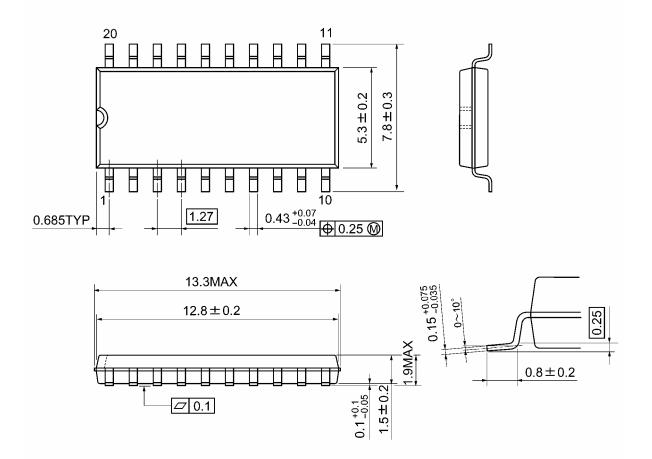




Weight: 1.30 g (typ.)

# **Package Dimensions**

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

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20070701-EN GENERAL

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